# **OBSOLETE - PART DISCONTINUED**





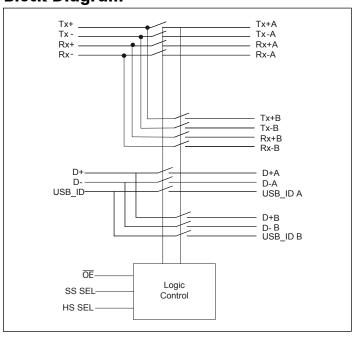
**PI3USB3102Q** 

### Automotive USB3.0 and USB2.0 Combo Switch

#### **Features**

- → AEC-Q 100 Qualified
- → 1:2 mux/demux for USB 3.0SS, 2.0HS, and 2.0FS signals
- → Switches Tx, Rx, Dx, and USB\_ID from USB3.0 connector
- → Insertion Loss for superspeed channels @ 2.5 GHz: -1.7dB
- → -3dB Bandwidth for superspeed channels: 4.7GHz
- → Return loss for superspeed channels @ 2.5GHz: -16dB
- → Low Bit-to-Bit Skew, 7ps max (between '+' and '-' bits)
- → Low Crosstalk for superspeed channels: -25dB@5.0 Gbps
- → Low Off Isolation for superspeed channels: -25dB@5.0 Gbps
- → V<sub>DD</sub> Operating Range: 3.3V +/-10%
- → ESD Tolerance: 2kV HBM
- → Low channel-to-channel skew, 35ps max
- → Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- → Halogen and Antimony Free. "Green" Device (Note 3)
- → Packaging (Pb-free & Green):
  - 32 TOFN (ZL)

# **Block Diagram**



## **Description**

Diodes' PI3USB3102Q USB3.0 and USB2.0 Combo Switch is a complete 1:2 switching solution for SuperSpeed USB 3.0 signals. PI3USB3102Q provides differential high-speed lanes for the USB3.0 4.8 Gbps TX and RX lanes as well as a differential lane for 480 Mbps USB 2.0 signals and the USB\_ID signal.

PI3USB3102Q can be used to connect two hosts to a single device or a single host to two devices.

PI3USB3102Q offers excellent signal integrity for high-speed signals and low power dissipation. Insertion loss is 1.7 dB and return loss is -16 dB at 2.5 GHz. Power dissipation is 6.6 mW maximum.

## **Application**

Routing of USB3.0 signals with low signal attenuation between source and sink.

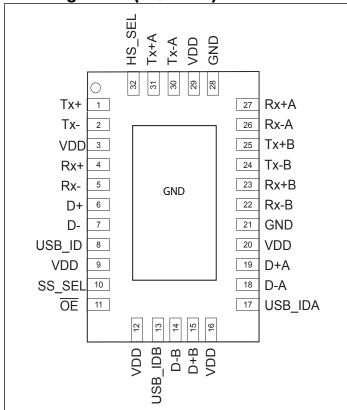
#### Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.





Pin Assignment (TQFN-32)



### **Truth Table**

$\overline{OE}$	SS_SEL	HS_SEL	Function			
Low	Low	Low	Port A active for all channels			
Low	Low	Low High Port A for SS, port B for HS and I				
Low	High	Low	Port B for SS, port A for HS and ID			
Low	High	High	Port B active for all channels			
High	x	X	I/O's are hi-z and IC is power down			

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## **Pin Description**

Pin#	Pin Name	Signal Type	Description	
1	Tx+	I/O	positive differential USB3.0 Tx signal for COM port	
2	Tx-	I/O	negative differential USB3.0 Tx signal for COM port	
3	VDD	Power	3.3V +/-10% power supply	
4	Rx+	I/O	positive differential USB3.0 Rx signal for COM port	
5	Rx-	I/O	negative differential USB3.0 Rx signal for COM port	
6	D+	I/O	positive differential USB2.0 signal for COM port	
7	D-	I/O	negative differential USB2.0 signal for COM port	
8	USB_ID	I/O	USB_ID for COM port	
9	VDD	Power	3.3V +/-10% power supply	
			switch logic control for SuperSpeed Path	
10	SS_SEL	I	If HIGH, then path B is selected for SuperSpeed channels only If LOW, then path A is selected for SuperSpeed channels only	
11	ŌĒ	I	Output enable. if $\overline{OE}$ is low, IC is enabled. If $\overline{OE}$ is high, then IC is power down and all I/Os are hi-z	
12	VDD	Power	3.3V +/-10% power supply	
13	USB_IDB	I/O	USB_ID for port B	
14	D-B	I/O	negative differential USB2.0 signal for port B	
15	D+B	I/O	positive differential USB2.0 signal for port B	
16	VDD	Power	3.3V +/-10% power supply	
17	USB_IDA	I/O	USB_ID for port A	
18	D-A	I/O	egative differential USB2.0 signal for port A	
19	D+A	I/O	ositive differential USB2.0 signal for port A	
20	VDD	Power	3.3V +/-10% power supply	
21	GND	Ground	Ground	
22	Rx-B	I/O	negative differential USB3.0 Rx signal for port B	
23	Rx+B	I/O	positive differential USB3.0 Rx signal for port B	
24	Tx-B	I/O	negative differential USB3.0 Tx signal for port B	
25	Tx+B	I/O	positive differential USB3.0 Tx signal for port B	
26	Rx-A	I/O	negative differential USB3.0 Rx signal for port A	
27	Rx+A	I/O	positive differential USB3.0 Rx signal for port A	
28	GND	Ground	Ground	
29	VDD	Power	3.3V +/-10% power supply	
30	Tx-A	I/O	negative differential USB3.0 Tx signal for port A	
31	Tx+A	I/O	positive differential USB3.0 Tx signal for port A	
			switch logic control for USB2.0 (D+/-) and USB_ID path	
32	HS_SEL	I	If High, path B is selected	
			If LOW, path A is selected	





## **Maximum Ratings**

(Above which useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	65°C to +150°C
Supply Voltage to Ground Potential	0.5V to +4.2V
DC Input Voltage	-0.5V to V <sub>DD</sub>
DC Output Current	120mA
Power Dissipation	
ESD:	
HBM per AEC-Q 100-002 (All Pins)	
CDM per AEC-Q 100-011 (All Pins)	250V

Note: Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## DC Electrical Characteristics for Switching over Operating Range

 $(TA = -40^{\circ}C \text{ to } +85^{\circ}C, VDD = 3.3V \pm 10\%)$ 

Parameter	Description	Test Conditions <sup>(1)</sup>	Min.	Typ.(1)	Max.	Units
V <sub>IH</sub>	Input HIGH Voltage	Guaranteed HIGH level	1.5			
$V_{IL}$	Input LOW Voltage	Guaranteed LOW level			0.75	V
$v_{IK}$	Clamp Diode Voltage, Dx	$V_{\mathrm{DD}} = \mathrm{Max.},  \mathrm{I_{\mathrm{IN}}} = -18 \mathrm{mA}$		-0.8	-1.1	
IIH	Input HIGH Current	$V_{DD} = Max., V_{IN} = V_{DD}$			±5	
$I_{IL}$	Input LOW Current	$V_{DD} = Max., V_{IN} = GND$			±5	μΑ
I <sub>OFF_HS/ID</sub>	I/O leakage when part is off for D+, D- and USB_ID signals only	$V_{DD} = 0V$ , $V_{INPUT} = 0V$ to 3.6V			20	
R <sub>ON_SS</sub>	On resistance between input to output for SuperSpeed signals	$V_{\rm DD}$ = 3.3V, Vinput = 0V to 1V, $I_{\rm INPUT}$ = 20mA		10	13	Ohm
R <sub>ON_FS</sub>	On resistance between input to output for USB2.0 FS signals (D+/D-)	$V_{\mathrm{DD}}$ = 3.3V, Vinput = 0 to 3.3V, $I_{\mathrm{INPUT}}$ = 20mA		7	9	Ohm
R <sub>ON_HS</sub>	On resistance between input to output for USB2.0 HS signals (D+/D-)	V <sub>DD</sub> = 3.3V, Vinput = -0.4V to +0.4V, I <sub>INPUT</sub> = 20mA		4	6	Ohm
USB_ID_I	Input voltage tolerance on USB_ID path				5.5	V
USB_ID_O	Output voltage on USB_ID path	USB_ID input from 0V to 5.25V			3.6	V

## Power Supply Characteristics (TA = $-40^{\circ}$ C to $+85^{\circ}$ C)

Parameter	Description	Test Conditions <sup>(1)</sup>	Min.	Typ.(1)	Max.	Units
$I_{CC}$	Quiescent Power Supply Current	$V_{DD}$ = Max., $V_{IN}$ = GND or $V_{DD}$			2	mA

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# Dynamic Electrical Characteristics over Operating Range (TA = -40° to +85°C, VDD = $3.3V \pm 10\%$ )

Parameter	Description	<b>Test Conditions</b>		Тур.	Max.	Units
X <sub>TALK</sub>	Crosstalk on SuperSpeed Channels	See Fig. 1 for Measurement Setup	f= 2.5 GHz	-25dB		dB
O <sub>IRR</sub>	OFF Isolation on SuperSpeed Channels	See Fig. 2 for Measurement Setup  f= 2.5 GHz		-22dB		uв
I <sub>LOSS</sub>	Differential Insertion Loss on SuperSpeed Channels	@5.0Gbps (see figure 3	3)	-1.7		dB
R <sub>loss</sub>	Differential Return Loss on SuperSpeed channels	@ 2.5GHz		-16		dB
BW_SS	Bandwidth -3dB for SuperSpeed path (Tx±/Rx±)	See figure 3		4.7		GHz
BW_HS	-3dB BW for USB high speed path (D+/-)	See figure 3		1.5		GHz
Tsw a-b	time it takes to switch from port A to port B				1	us
Tsw b-a	time it takes to switch from port B to port A				1	us
Tstartup	Vdd valid to channel enable				10	us
Twakeup	Enabling output by changing $\overline{\text{OE}}$ from low to High				10	us

#### Note:

# Switching Characteristics (T<sub>A</sub>= -40° to +85°C, $V_{DD}=3.3V\pm10\%$ )

Parameter	Description		Тур.	Max.	Units
T <sub>pd</sub>	Propagation delay (input pin to output pin)		80		ps
t <sub>b-b</sub>	Bit-to-bit skew within the same differential pair		5		ps
tch-ch	Channel-to-channel skew			35	ps

<sup>1.</sup> For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.

<sup>2.</sup> Typical values are at  $V_{DD}$  = 3.3V,  $T_A$  = 25°C ambient and maximum loading.





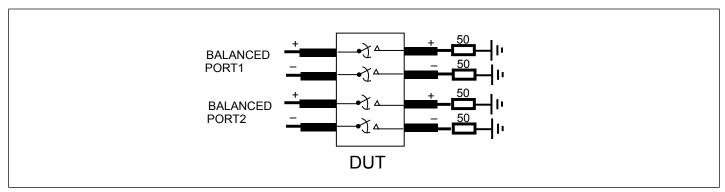


Fig 1. Crosstalk Setup

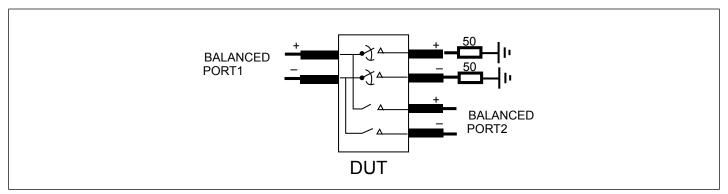


Fig 2. Off-isolation setup

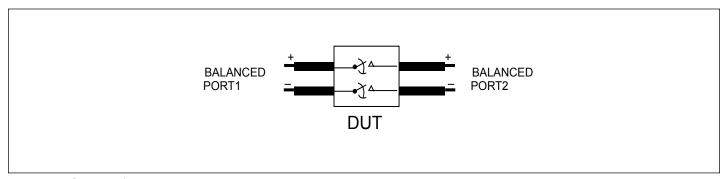


Fig 3. Differential Insertion Loss set up



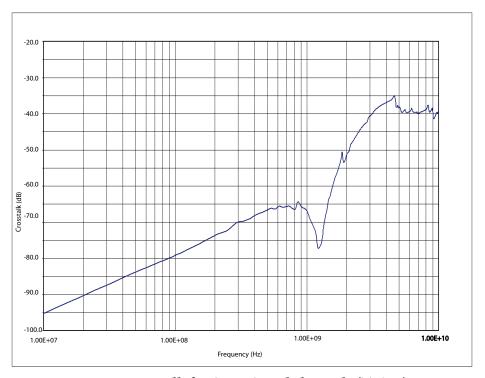


Fig 4. Xtalk for SuperSpeed channels (Tx/Rx)

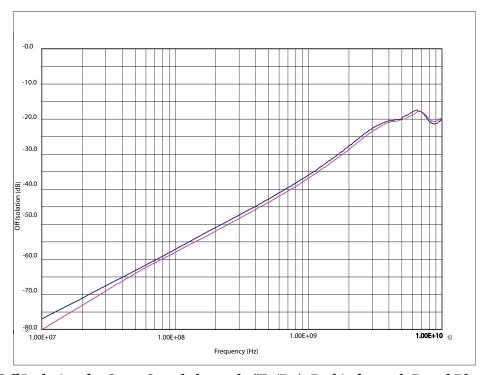


Fig 5. Off Isolation for SuperSpeed channels (Tx/Rx). Red is for path B and Blue is for path A





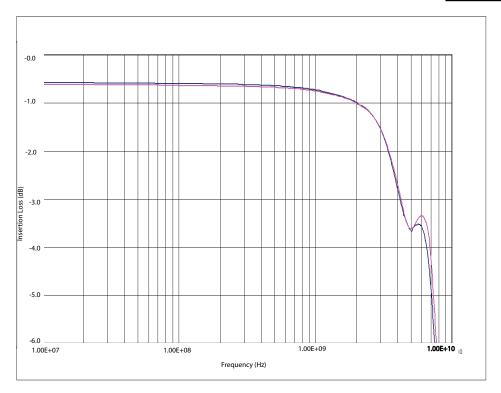
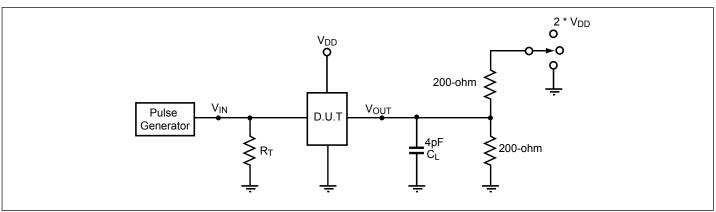


Fig 6. Insertion Loss for SuperSpeed channels (Tx/Rx). Red is for path B and Blue is for path A

### Test Circuit for Electrical Characteristics (1-5)



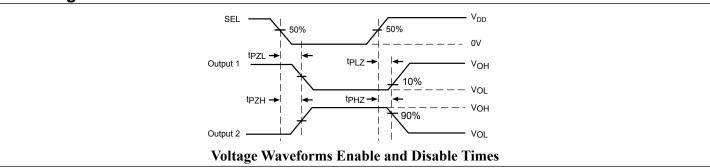
#### Notes:

- 1.  $C_L$  = Load capacitance: includes jig and probe capacitance.
- 2.  $R_T$  = Termination resistance: should be equal to  $Z_{OUT}$  of the Pulse Generator
- 3. Output 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
- 4. Output 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- 5. All input impulses are supplied by generators having the following characteristics: PRR  $\leq$  MHz,  $Z_O = 50\Omega$ ,  $t_R \leq$  2.5ns,  $t_F \leq$  2.5ns.
- 6. The outputs are measured one at a time with one transition per measurement.





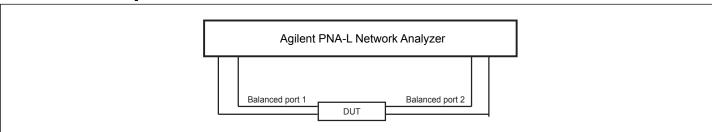
**Switching Waveforms** 



### **Switch Positions**

Test	Switch
t <sub>PLZ</sub> , t <sub>PZL</sub> (output on B-side)	2 * Vdd
t <sub>PHZ</sub> , t <sub>PZH</sub> (output on B-side)	GND
Prop Delay	Open

## **Test Circuit for Dynamic Electrical Characteristics**



# **Part Marking**

ZL Package

PI3USB 3102QZLE O YYWWXX

YY: Year

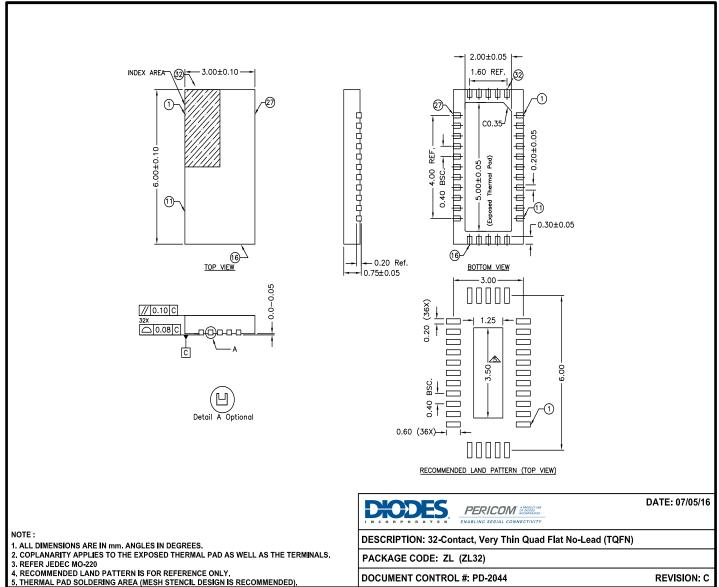
WW: Workweek

1st X: Assembly Code 2nd X: Fab Site Code





## Packaging Mechanical: 32-TQFN (ZL)



6-0142

### For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

## **Ordering Information**

Ordering Code	Package Code	Package Description
PI3USB3102QZLEX	ZL	32-Contact, Very Thin Quad Flat No-Lead (TQFN)

#### Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. E = Pb-free and Green
- 5. X suffix = Tape/Reel